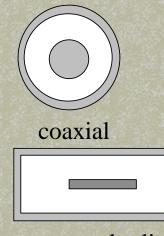
Planar Transmission Line

มีกกุฎ หรือสมาริกัญ หรือมาไม้กับ เรื่อมาไม้กับ หรือมาไม้กับ เรื่อมาไม้กับ หรือมาไม้กับ เรื่อมาไม้กับ การเป็นสีว่า การเป็นสีว่า การเป็นสีว่า การเป็นสีว่า การเป็นสีว่า การเป็นสีว่า การเป็นสีว่า การเป็นสีว่า การเป็น การเมืองการเรื่องการเห็น ถึงการเห็น ถึงการเห็น ถึงการเห็น ถึงการเห็น ถึงการเห็น ถึงการเป็นการเห็น ถึงการเห็น กา

various planar transmission line structures are shown here:

stripline	slot line
microstrip	coplanar
line	line

the strip line was developed from the square coaxial



rectangular line

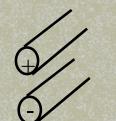
sq	uare coa	axial
fla	at stripli	ne

since the stripline has only 1 dielectric, it supports TEM wave, however, it is difficult to integrate with other discrete elements and excitations

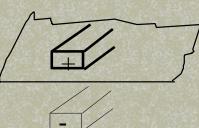
microstrip line is one of the most popular types of planar transmission line, it can be fabricated by photolithographic techniques and is easily integrated with other circuit elements

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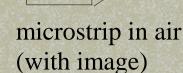
the following diagrams depicts the evolution of microstrip transmission line



two-wire line



single-wire above ground (with image)



microstrip with grounded slab

- a microstrip line suspended in air can support TEM wave
- a microstrip line printed on a grounded slab does not support TEM wave
- the exact fields constitute a hybrid TM-TE wave
- when the dielectric slab become very thin (electrically), most of the electric fields are trapped under the microstrip line and the fields are essentially the same as those of the static case, the fields are quasi-static

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one can define an effective dielectric constant so that the phase velocity and the propagation constant can be defined as

 $\mathbf{v_p} = \frac{\mathbf{c}}{\sqrt{\mathbf{\epsilon_e}}} - - - -(47)$

$$\begin{split} \beta &= k_0 \sqrt{\epsilon_e} - - - (48) \\ \text{the effective dielectric constant is bounded by} \\ 1 &< \epsilon_e < \epsilon_r \text{ , it also depends on the slab} \\ \text{thickness d and conductor width, W} \end{split}$$

- design formulas have been derived for microstrip lines
- these formulas yield approximate values which are accurate enough for most applications
- they are obtained from analytical expressions for similar structures that are solvable exactly and are modified accordingly

or they are obtained by curve fitting numerical data

the effective dielectric constant of a microstrip line is given by $\epsilon_{r} = \frac{\epsilon_{r} + 1}{2} + \frac{\epsilon_{r} - 1}{2} \frac{1}{\sqrt{1 + 12d/W}} - - - - (49)$

the characteristic impedance is given by for W/d \leq 1 60 (8d W)

$$Z_0 = \frac{60}{\sqrt{\epsilon_r}} \ln \left(\frac{\delta u}{W} + \frac{w}{4d} \right) - - -(50)$$

For W/d \geq 1

 $Z_{0} = \frac{120\pi}{\sqrt{\epsilon_{r} [W/d + 1.393 + 0.667 \ln(W/d + 1.444)]}} - -(51)$

for a given characteristic impedance Z_{0} and dielectric constant ϵ_{r} , the W/d ratio can be found as

W/d =
$$\frac{8e^{A}}{e^{2A}-2}$$
 ---- (52) for W/d<2

W/d = $\frac{2}{\pi}$ [B-1-ln(2B-1)+ $\frac{\epsilon_{r}-1}{2\epsilon_{r}}$ × $\{ \ln(B-1) + 0.39 - \frac{0.61}{\epsilon_r} \}] - - - -(53)$ for W/d > 2 Where $A = \frac{Z_0}{60} \sqrt{\frac{\epsilon_r + 1}{2}} + \frac{\epsilon_r - 1}{\epsilon_r + 1} (0.23 + \frac{0.11}{\epsilon_r})$ And $\mathbf{B} = \frac{377\pi}{2\mathbf{Z_o}\sqrt{\epsilon_r}}$

for a homogeneous medium with a complex dielectric constant, the propagation constant is written as

$$\gamma = \alpha_d + j\beta = \sqrt{k_c^2 - \kappa^2}$$

$$\gamma = \sqrt{k_c^2 - \omega^2 \mu_0 \varepsilon_0 \varepsilon_r (1 - j \tan \delta)}$$

note that the loss tangent is usually very small

$$\gamma = \sqrt{k_c^2 - k^2 + jk^2} \tan \delta$$

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Note that $(1+x)^{1/2} = 1+x/2$ where x is small

therefore, we have

$$\gamma = \sqrt{k_{c}^{2} - k^{2}} + \frac{jk^{2} \tan \delta}{2\sqrt{k_{c}^{2} - k^{2}}} - - - (54)$$

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Note that $j\beta = \sqrt{k_c^2 - k^2}$

for small loss, the phase constant is unchanged when compared to the lossless case

the attenuation constant due to dielectric loss is therefore given by $\alpha_{d} = \frac{k^{2} \tan \delta}{2\beta}$ Np/m (TE or TM) (55)

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For TEM wave $\mathbf{k} = \beta$, therefore

 $\alpha_{d} = \frac{k \tan \delta}{2} \text{ Np/m (TEM) (56)}$ for a microstrip line that has inhomogeneous medium, we multiply Eq. (56) with a filling factor $\frac{\varepsilon_{r}(\varepsilon_{e} - 1)}{\varepsilon_{e}(\varepsilon_{r} - 1)}$

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$$\alpha_{d} = \frac{k_{0}\sqrt{\epsilon_{e}}\tan\delta}{2} \quad \frac{\epsilon_{r}(\epsilon_{e}-1)}{\epsilon_{e}(\epsilon_{r}-1)} \qquad \frac{k_{0}\epsilon_{r}(\epsilon_{e}-1)}{2\sqrt{\epsilon_{e}}(\epsilon_{r}-1)}$$

the attenuation due to conductor loss is given by $\alpha_c = \frac{R_s}{Z_0 W}$

(58) Np/m where $R_{s} = \sqrt{\omega \mu_{0} / (2\sigma)}$

 $\mathbf{R}_{\mathbf{s}}$ is called the surface resistance of the conductor

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note that for most microstrip substrate, the dielectric loss is much more significant than the conductor loss

at very high frequency, conductor loss becomes significant

MPONENTS

- ost widely used guide structures in component development are image guides.
- Best potential at freq above 60GHz
- Use of dielectric H-guide and groove-guide structures at for freq. beyond 100GHz.
- Realizing high-performance antennas.
- Feed structures for array antennas.
- Incorporation of active devices in dielectric guides is more difficult than in suspended striplines or fin lines
- Realizing dynamically controlled devices such as switches, phase shifters and attentuators.